查询"2<u>SA1204_07"做</u>解<mark>®</mark>A Transistor Silicon PNP Epitaxial Type (PCT process)

2SA1204

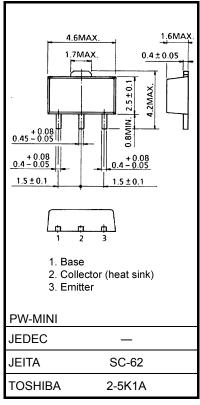
Audio Frequency Amplifier Applications

Unit: mm

- High DC current gain: hFE = 100 to 320
- Suitable for output stage of 1 watts amplifier
- Small flat package
- PC = 1.0 to 2.0 W (mounted on a ceramic substrate)
- Complementary to 2SC2884

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	-35	V	
Collector-emitter voltage	V _{CEO}	-30	٧	
Emitter-base voltage	V _{EBO}	-5	٧	
Collector current	IC	-800	mA	
Base current	ΙΒ	-160	mA	
Collector power dissipation	PC	500	mW	
	P _C (Note 1)	1000		
Junction temperature	Tj	150	°C	
Storage temperature range	T _{stg}	−55 to 150	°C	



Weight: 0.05 g (typ.)

Note 1: Mounted on a ceramic substrate (250 mm² × 0.8 t)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

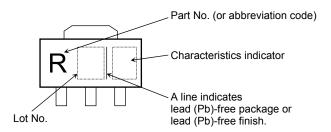
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Energial Characteristics (Ta = 25°C)

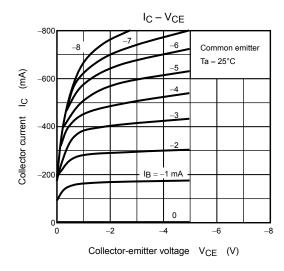
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -35 \text{ V}, I_{E} = 0$	_	_	-0.1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$	_	_	-0.1	μA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = -10 mA, I _B = 0	-30	_	_	V
DC current gain	h _{FE (1)} (Note 3)	V _{CE} = -1 V, I _C = -100 mA	100	_	320	
	h _{FE (2)}	V _{CE} = -1 V, I _C = -700 mA	35	_	_	
Collector-emitter saturation voltage	V _{CE} (sat)	$I_C = -500 \text{ mA}, I_B = -20 \text{ mA}$	_	_	-0.7	٧
Base-emitter voltage	V _{BE}	V _{CE} = -1 V, I _C = -10 mA	-0.5	_	-0.8	V
Transition frequency	f _T	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	_	120	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz	_	19	_	pF

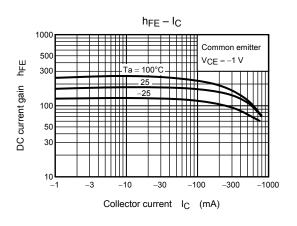
Note 3: $h_{FE(1)}$ classification O: 100 to 200, Y: 160 to 320

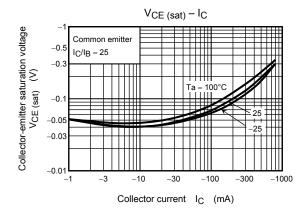
Marking

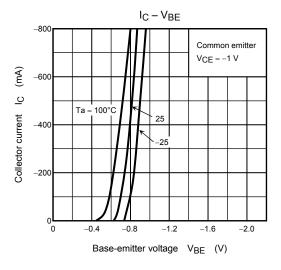


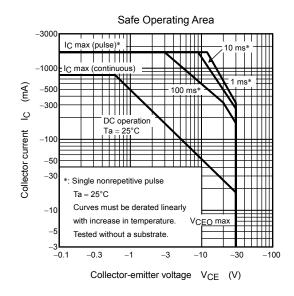
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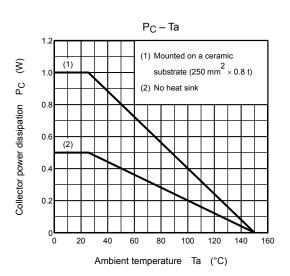












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